



FUKUCOM COMPANY LTD.

福 靈 有 限 公 司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,
KWUN TONG, KOWLOON, HONG KONG.

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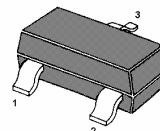
MMBD3004 / SE / CC / CA

Silicon Epitaxial Planar Switching Diode

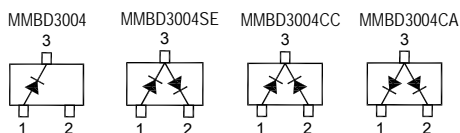
High Voltage Switching Diode

Features

- Fast switching speed
- High Conductance
- High Reverse Breakdown Voltage Rating



MMBD3004 Marking Code: "HC"
 MMBD3004SE Marking Code: "PY"
 MMBD3004CC Marking Code: "PZ"
 MMBD3004CA Marking Code: "RA"
 SOT-23 Plastic Package

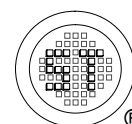


Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	350	V
Working Peak Reverse Voltage	V_{RWM}	300	V
DC Blocking Voltage	V_R	300	V
Continuous Forward Current	I_F	225	mA
Peak Repetitive Forward Current	I_{FRM}	625	mA
Non-Repetitive Peak Forward Surge Current	I_{FSM}	1 4	A
		at $t = 1\text{ s}$ at $t = 1\text{ }\mu\text{s}$	
Power Dissipation	P_d	350	mW
Operating and Storage Temperature Range	T_j, T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage	V_F	-	0.87	V
at $I_F = 20\text{ mA}$		-	1	
at $I_F = 100\text{ mA}$		-	1.25	
Reverse Current	I_R	-	100	nA
at $V_R = 240\text{ V}$		-	100	μA
at $V_R = 240\text{ V}, T_j = 150\text{ }^\circ\text{C}$				
Reverse Breakdown Voltage	$V_{(BR)R}$	350	-	V
at $I_R = 100\text{ }\mu\text{A}$				
Total Capacitance	C_T	-	5	pF
at $V_R = 0, f = 1\text{ MHz}$				
Reverse Recovery Time	t_{rr}	-	50	ns
at $I_F = I_R = 30\text{ mA}, I_{tr} = 0.1 I_R, R_L = 100\text{ }\Omega$				





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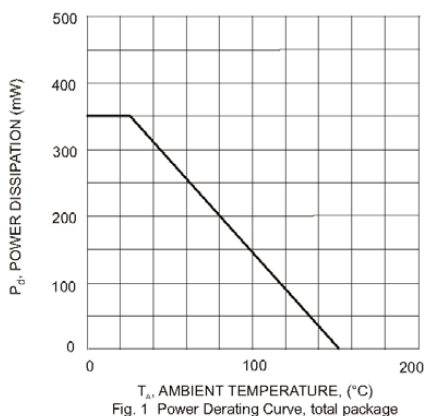


Fig. 1 Power Derating Curve, total package

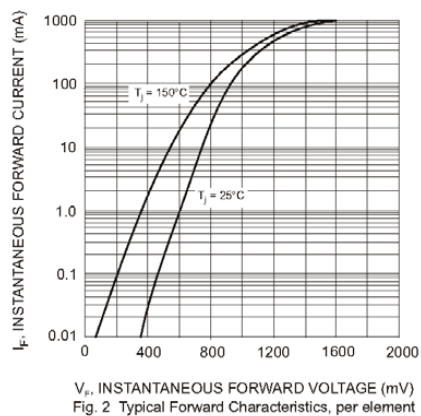


Fig. 2 Typical Forward Characteristics, per element

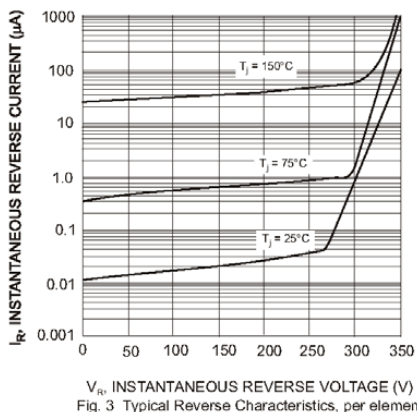


Fig. 3 Typical Reverse Characteristics, per element

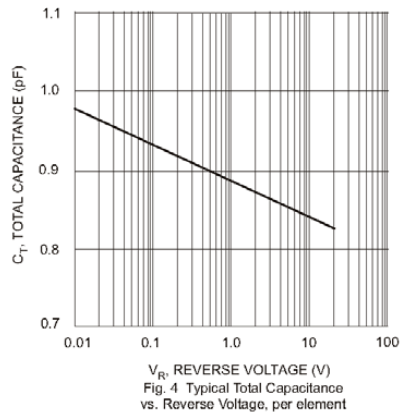


Fig. 4 Typical Total Capacitance vs. Reverse Voltage, per element

